

Omni-directional Microphone with High SNR Digital Output (Top Port)

DESCRIPTION

The ZTS6235 is a high quality, low cost, low power digital output top-ported omni-directional MEMS microphone. ZTS6235 consists of a MEMS microphone element and a preamplifier. ZTS6235 has a high SNR and flat wideband frequency response with $\pm 2\text{dB}$ in 10KHz. Sensitivity is a single tone distribution in a narrow window with under $\pm 1\text{dB}$, resulting in natural sound with high intelligibility. Due to built-in filter, ZTS6235 shows high immunity to EMI.

The ZTS6235 is available in a thin 3.50mm \times 2.00mm \times 1.0mm surface-mount package. It is reflow solder compatible with no sensitivity degradation. The ZTS6235 is halide free.

APPLICATIONS

- Mobile telephones
- PDAs
- Digital video cameras
- Portable media devices with audio input

ORDERING INFORMATION

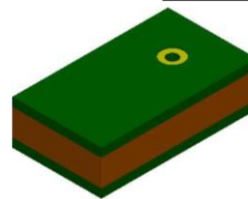
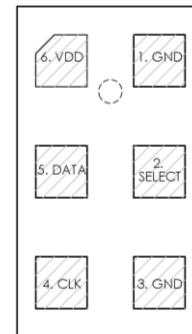
PART	RoHS	Ship, Quantity
ZTS6235	Yes	Tape and Reel, 5.2K

FEATURES

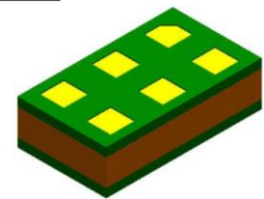
- 3.50mm \times 2.00mm \times 1.0mm surface-mount package
- Stable sensitivity over power supply range of 1.60V-3.60V
- SNR of 64dB(A)
- Sensitivity of -26dB FS
- Multi Chip Module (MCM) Package

Pins Configuration and Description

Bottom View



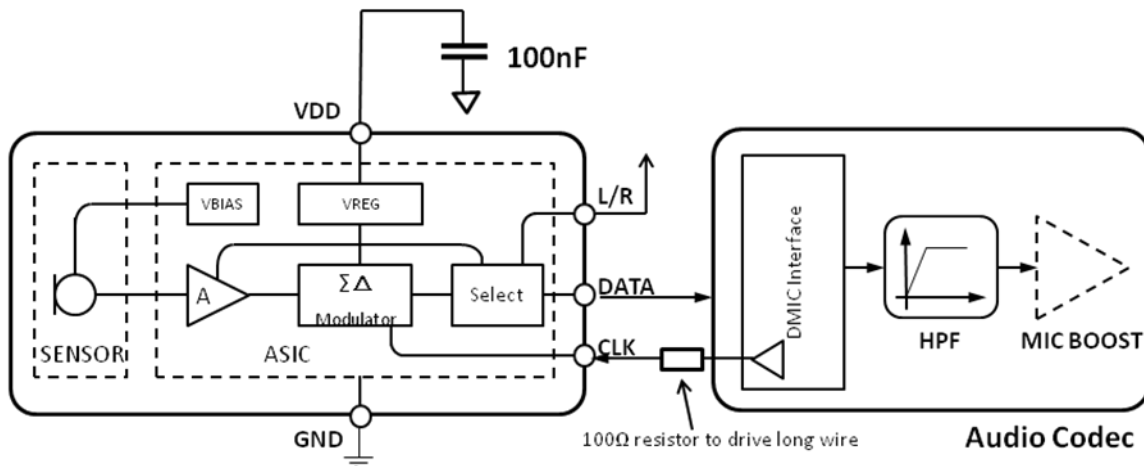
Top



Bottom

Isometric Views of ZTS6235 Microphone Package

Typical Applications



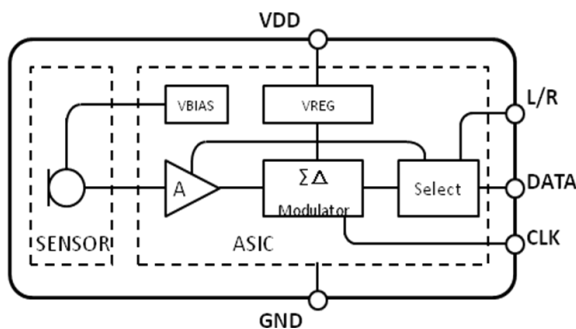
Label	Select	Drives Data After	High-Z After
Data_H	High	Rising Clock Edge	Falling Clock Edge
Data_L	Low (default)	Falling Clock Edge	Rising Clock Edge

Absolute Maximum Ratings

CLOCK to Ground -0.3V to +6.0V
 SELECT, V_{DD}, DATA to Ground -0.3V to +6.0V
 Input Current ±5mA
 Operating Temperature Range -40°C to +100°C
 Storage Temperature Range -40°C to +100°C

CAUTION: Stresses above those listed in “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Microphone Block Diagram



Electro-Static Discharge Sensitivity

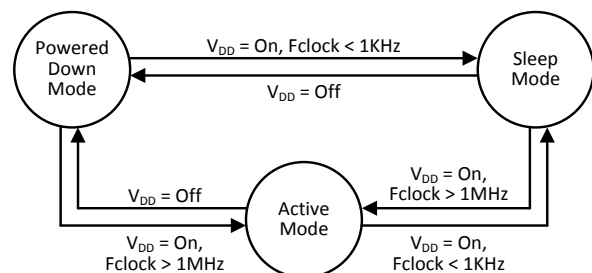


This integrated circuit can be damaged by ESD. It is recommended that all integrated circuits be handled with proper precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure.

Pin	Symbol	Description
1	GND	Ground.
2	SELECT	Select.
3	GND	Ground.
4	CLOCK	Clock.
5	DATA	Output.
6	VDD	Power Supply (V _{DD}).

Pins Description

Microphone State Diagram



Specifications

($T_A = +15^{\circ}\text{C} \sim +25^{\circ}\text{C}$, $V_{DD} = +1.8\text{V}$, $f_{\text{clock}} = 2.4\text{MHz}$, R.H. = 60%~70%, no load, unless otherwise noted.)

PARAMETER	Symbol	TEST CONDITIONS			MIN	TYP	MAX	UNIT
Supply Voltage (Note 1)	V _{DD}				1.60		3.60	V
Current Consumption (Note 1,6)	I _{DD}					600		μA
Standby Current (Sleep Mode) (Note 5,6)	I _{STANDBY}	f _{clock} < 1KHz				5	15	μA
Directivity					Omni-directional			
Sensitivity (Note 1)	S	94dB SPL @ 1KHz			-27	-26	-25	dB FS
Signal to Noise Ratio	SNR	94dB SPL @ 1KHz, A-weighted				64		dB(A)
Total Harmonic Distortion	THD	115dB SPL @ 1KHz					2	%
		120dB SPL @ 1KHz					10	%
Power Supply Rejection	PSR	217Hz, 100mV Vp-p, square wave on V _{DD}	V _{DD} =1.8V V _{DD} =3.3V			-80 -80		dB FS
Polarity		Increasing sound pressure			Increasing density of 1's			
Fall-Asleep Time (Note 2,3)		V _{DD} = On, f _{clock} < 1KHz					10	ms
Wake-Up Time (Note 2,4)		V _{DD} = On, f _{clock} ≥ 1MHz					10	ms
Short Circuit Output Current	I _{SC}	Grounded output pin				1	10	mA
Output Load	C _{LOAD}						100	pF
Data Format					1/2 cycle PDM			
Clock Frequency	f _{clock}				1.0		3.25	MHz
Clock Duty Cycle					40		60	%
Clock Rise Time	t _{cr}						10	ns
Clock Fall Time	t _{ct}						10	ns
Logic Input/Output Low	V _{IOL}				I _{out} = 1mA			-0.3
Logic Input/Output High	V _{IOH}	I _{out} = 1mA			0.65×V _{DD}		V _{DD} +0.3	V
Delay Time for Valid Data	t _{dv}	CLK = 3.072MHz Oscilloscope: APx525 (probe Cin = 24pF)	Data Trans High	1.8	26		82	ns
				3.3	20		80	
			Data Tran Low	1.8	25		80	
				3.3	21		81	
Delay Time for High Z	t _{dz}	CLK = 3.072MHz, Oscilloscope: APx525 (probe Cin = 24pF)	Data Trans High	1.8	0		25	ns
				3.3	0		24	
			Data Trans Low	1.8	0		26	
				3.3	0		25	
Settling time	t _s			1.8V 3.3V		2.65	5.5	ms
Startup Time		Powered Down →Active Mode		1.8V		2.65	5.5	ms
				3.3V		2.45	5.3	

Note 1: 100% tested.

Note 2: Valid microphone states are: Power Down Mode (mic off), Sleep Mode (low current, no output, fast start-up), and Active Mode (normal operation).

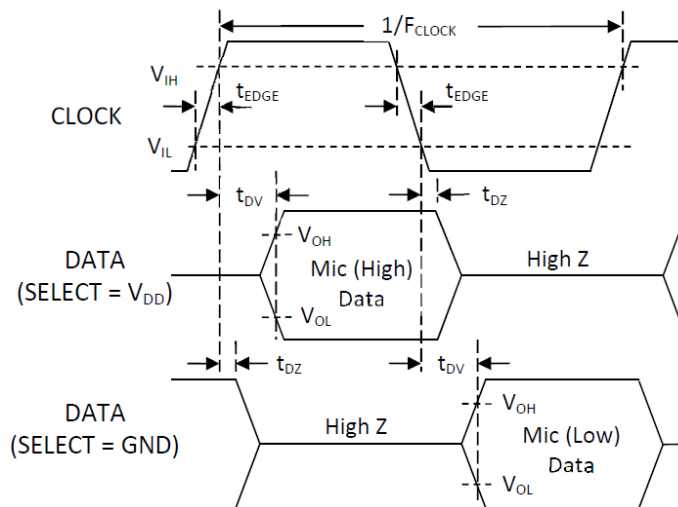
Note 3: Time from $f_{\text{clock}} < 1\text{KHz}$ to sleep current specification is met when transitioning from Active to Sleep Mode.

Note 4: Time from $f_{\text{clock}} \geq 1\text{MHz}$ to all applicable specifications when transitioning from Sleep to Active Mode.

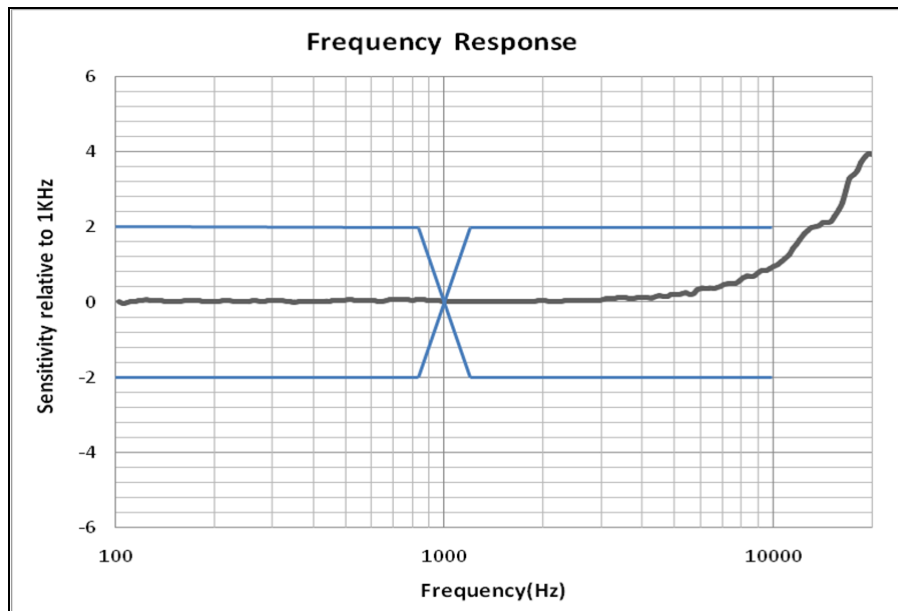
Note 5: $\Delta I_{DD} = 0.5 \times V_{DD} \times C_{LOAD} \times f_{clock}$

Note 6: Specified max values are measured at $V_{DD} = +3.6V$.

Timing Diagram



Typical Performance Characteristics

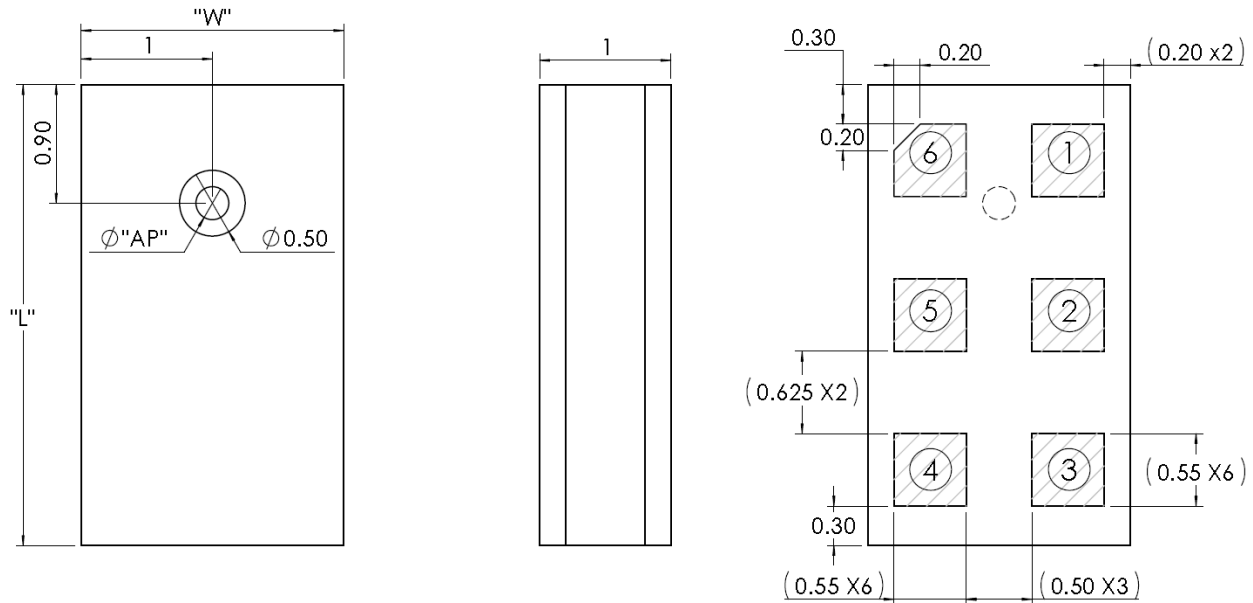


Reliability Tests

The microphone sensitivity after stress must deviate by no more than $\pm 3\text{dB}$ from the initial value.

1. Heat Test, Operational	Temperature: $125\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Applied
2. Cold Test, Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Applied
3. Heat Test, Non-Operational	Temperature: $125\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Not Applied
4. Cold Test, Non-Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Not Applied
5. Thermal Shock Test, Non-Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ and $125\pm 3^{\circ}\text{C}$ Duration: 30 minutes each, during 5 minutes ramp, 256 cycles Voltage: Not applied
6. Temperature humidity storage	Temperature: $85\pm 3^{\circ}\text{C}$ Humidity: $85\pm 3\%\text{RH}$ Duration: 1000 hours
	Temperature: $65\pm 3^{\circ}\text{C}$ Humidity: $95\pm 3\%\text{RH}$ Duration: 168 hours
7. Free Fall Test 1.5m	Placed inside test fixture and dropped on concrete from height 1.5m. 4 times by each surface and corner
8. Vibration	4 cycles of 20 to 2000 Hz sinusoidal sweep with 20G peak acceleration lasting 12 minutes in X, Y, and Z directions
9. Mechanical Shock	5 pulses of 10000g in each of the $\pm X$, $\pm Y$, and $\pm Z$ directions
10. Electrostatic Discharge Test	Capacitance: 150pF Resistance: 330Ω Duration: 10 times Air Discharge: Level 4 (+/-15kV) Direct contact discharge: Level 4 (+/-8kV)
11. Human Body Mode	± 2000 Volt
12. Charged-Device Model	± 250 Volt
13. Reflow	5 reflow cycles with peak temperature of 260°C
14. Solderability	$245\pm 5^{\circ}\text{C}$, 5sec, 95% Tin on pad surface
15. Tumble test	300 tumbles from a height of 1m onto a steel base.
16. HAST	Temperature: $130\pm 3^{\circ}\text{C}$ Humidity: $85\pm 3\%\text{RH}$ Duration: 96 hours Voltage: Applied
17. Air Blow	0.45MPa, distance 3cm, time 10s

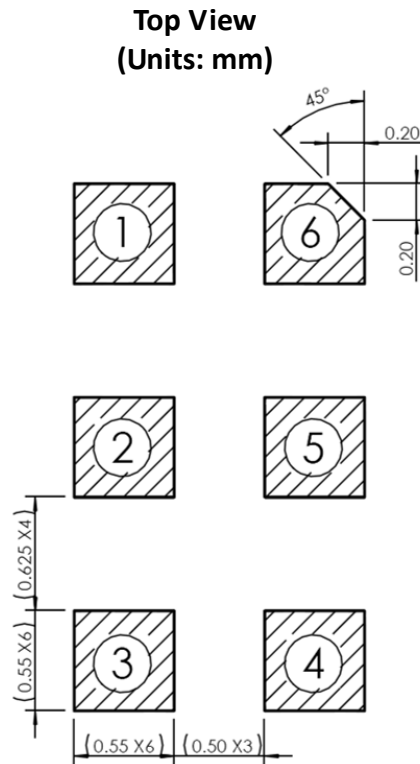
MECHANICAL SPECIFICATIONS



ITEM	DIMENSION	TOLERANCE	UNITS
Length (L)	3.50	± 0.10	mm
Width (W)	2.00	± 0.10	mm
Height (H)	1.00	± 0.10	mm
Acoustic Port (AP)	$\phi 0.25$	± 0.050	mm

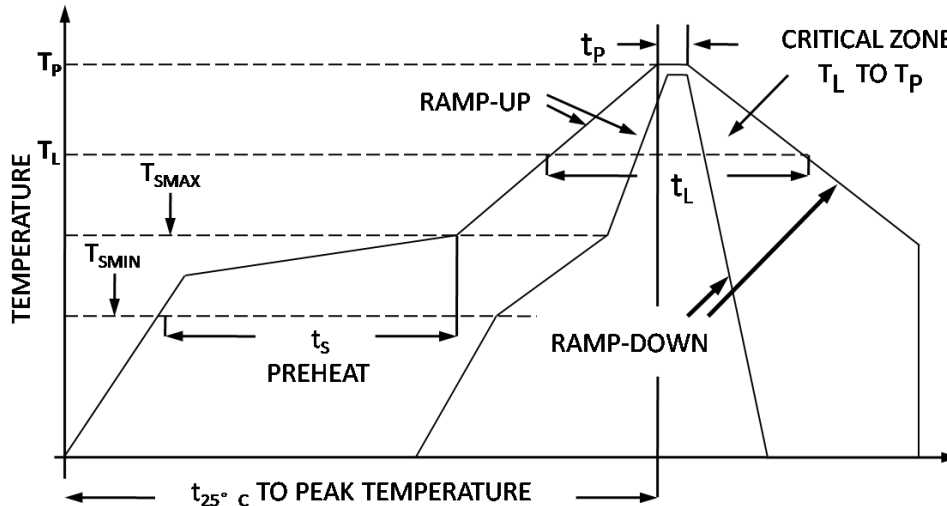
RECOMMENDED CUSTOMER LAND PATTERN

The recommended PCB land pattern for the ZTS6235 should have a 1:1 ratio to the solder pads on the microphone package. Care should be taken to avoid applying solder paste to the sound hole in PCB. The dimensions of suggested solder paste pattern refer to the land pattern **which should be shrunk by 0.025 per side**.



SOLDER FLOW PROFILE

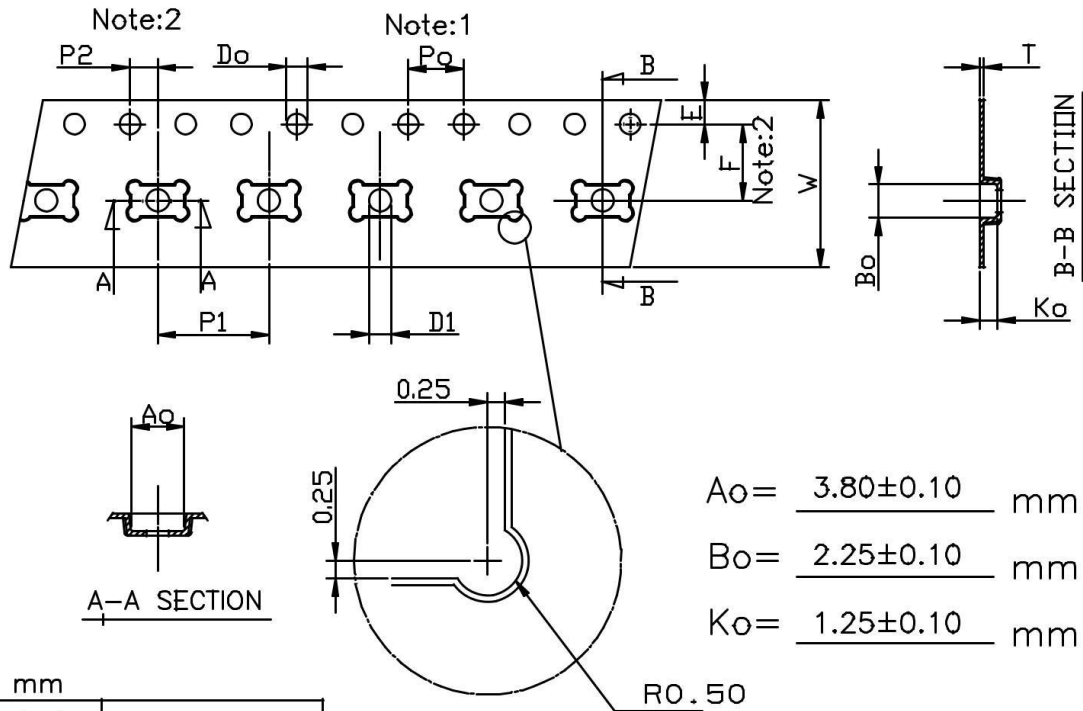
The reflow profile specified in this section describes expected maximum heat exposure of components during the reflow process of NMP product PWBs. Temperature is measured on top of component. All components have to tolerate at least this profile five times (5x) without affecting electrical performance, mechanical performance or reliability.



Pb-free and Sn63/Pb37 reflow profile requirements for soldering heat resistance:

Parameter		Reference	Pb-Free	Sn63/Pb37
Average Ramp Rate		T_L to T_P	1.25°C/sec max	1.25 °C /sec max
Preheat	Minimum Temperature	T_{SMIN}	100°C	100 °C
	Maximum Temperature	T_{SMAX}	200°C	150 °C
	Time	T_{SMIN} to T_{SMAX}	60sec to 120sec	60sec to 120sec
Ramp-Up Rate		T_{SMAX} to T_L	1.25°C/sec	1.25 °C /sec
Time Maintained Above Liquidous		t_L	60sec to 150sec	60sec to 150sec
Liquidous Temperature		T_L	217°C	183 °C
Peak Temperature		T_P	260°C +0°C/-5°C	215 °C +3 °C /-3 °C
Time Within +5°C of Actual Peak Temperature		t_p	20 sec to 30 sec	20 sec to 30 sec
Ramp-Down Rate		T_{peak}	6°C/sec max	6 °C /sec max
Time +25°C (t_{250C}) to Peak Temperature			8 min max	6 min max

PACKAGING



Unit: mm

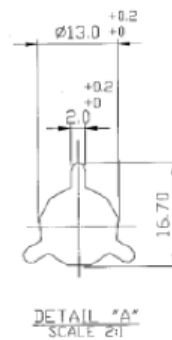
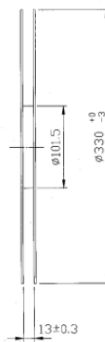
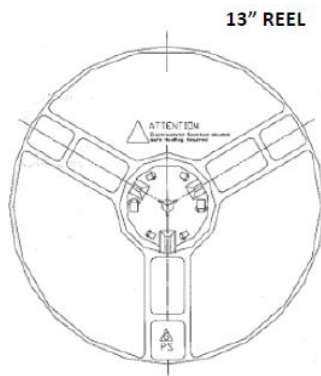
Symbol	Spec.
Po	4.0±0.10
P1	8.0±0.10
P2	2.0±0.10
Do	1.50 ^{+0.1} ₋₀
D1	1.50(MIN)
E	1.75±0.10
F	5.50±0.05
10Po	40.0±0.20
W	12.0 ^{+0.3} _{-0.1}
T	0.30±0.05

Notice:

1. 10 Sprocket hole pitch cumulative tolerance is ±0.2mm
2. Pocket position relative to sprocket hole measured as true position of pocket not pocket hole.
3. Ao & Bo measured on a plane 0.3mm above the bottom of the pocket to top surface of the carrier.
4. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
5. Carrier camber shall be not than 1mm per 100mm through a length of 250mm.

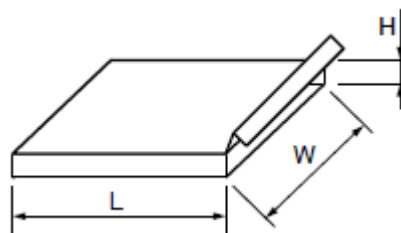
A	Original	E.Chang	2016/4/8
REV	DESCRIPTION	BY	DATE

SCALE:	MATERIAL: Polystyrene Black	TITLE: 6235
UNIT: MM	TREATMENT: Surface Resistivity 10 ⁵⁻⁷ Ωm/Square	DWG.NO: P1208-059401
PROJ:	DESIGNED: Elisha	APPROVED: Roger
DATE: 2016/4/8	DATE: 2016/4/8	DATE: 2016/4/8
HSUAN SHAN PACKING CORPORATION		



Part NO.	Reel Diameter	Quantity Per Reel	Quantity Per Inner Box	Quantity Per Outer Box
ZTS6235	13"	5200	5200	46800

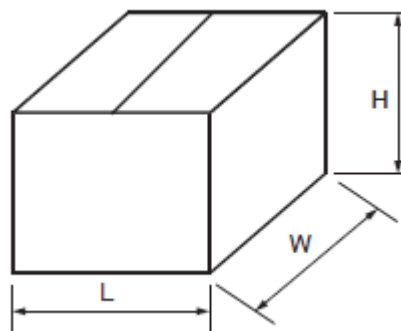
Dimensions for Inner Box



Unit : mm

L	W	H
335	339	45

Dimensions for Outer Box



Unit : mm

L	W	H
445	360	372